# D ynam ical nuclear polarization and nuclear m agnetic elds in sem iconductor nanostructures

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W e investigate the dynam ic nuclear polarization from the hyper ne interaction between nonequilibrium electronic spins and nuclear spins coupled to them in sem iconductor nanostructures. W e derive the tim e and position dependence of the induced nuclear spin polarization and dipolar m agnetic elds. In G aA s/A IG aA s parabolic quantum wells the nuclear spin polarization can be as high as 80% and the induced nuclearm agnetic elds can approach a few gauss with an associated nuclear resonance shift of the order of kH z when the electronic system is 100% spin polarized. These elds and shifts can be tuned using sm all electric elds. W e discuss the implications of such control for optical nuclear m agnetic resonance experim ents in low-dim ensional sem iconductor nanostructures.

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### I. IN TRODUCTION

Coherent control of the spin degrees of freedom in low dimensional sem iconductor structures may lead to spin based electronic devices and quantum information  $processing^{1/2}$ . The practical realization of quantum com puting requires the preparation, m anipulation, and m easurement of pure quantum states<sup>3,4,5</sup>. Nuclear spins are ideal candidates, as all required conditions can be achieved based on the hyper ne interaction between electronic and nuclear spins<sup>5,6</sup>. Despite the local character of the hyper ne interaction, single nuclear spin manipulation is hard to achieve, an inconvenience which can be overcom e by using instead nuclear spin clusters<sup>7</sup>. For GaAs quantum wells and quantum dots the nuclear spin coherence tim e can be as long as a second<sup>8,9</sup>, m uch longer than the electron spin coherence time, of the order of 100 ns (Ref. 10).

Control over the nuclear spin dynamics in semiconductor nanostructures is realized by various methods. Control of collective excitations<sup>11,12</sup> can modify the enhanced nuclear spin relaxation times in a GaAs quantum well (QW). Adjacent ferrom agnetic layers can \imprint" nuclear spin<sup>13</sup> in n-type GaAs OW 's. A exible method of nuclear spin manipulation, using gate voltages to electrically address a wide distribution of polarized nuclei within an AlGaAs parabolic quantum well (PQW), was recently dem onstrated<sup>14</sup>. Optically injected spin polarized electrons transfer their spin polarization to the nuclear population via dynam ic nuclear polarization (DNP)<sup>15</sup>, resulting in a position dependent nuclear polarization within the PQW .G ate voltages are then used to shift the electron population and thus produce polarized nuclei with di erent probabilities at various positions in the PQW . The position dependent nuclear polarization wasm easured by time resolved Faraday rotation (TRFR) experiments, which showed<sup>14</sup> that a 8 nm wide distribution of polarized nuclei can be manipulated electrically over a range of 20 nm .

Here we derive general formulas describing the nuclear polarization, and resulting nuclear dipolar elds,

achieved dynam ically in low dimensional sem iconductor nanostructures due to the hyper ne interaction between electronic and nuclear spins. Just as was found for nuclear and electron relaxation times<sup>9</sup>, the central physical quantity determ ining the nuclear polarization is the electronic local density of states (ELDOS) at the nuclear position. The position dependence of the induced nuclear polarization in sem iconductor nanostructures is shown to be a function of the initial polarization of the electronic population and various nuclear interactions which lead to nuclear spin relaxation. We calculate how the nuclear polarization within the sem iconductor nanostructure can be manipulated with electric elds by changing the EL-DOS at particular locations. Our results are relevant for nuclear magnetic resonance (NMR) and TRFR experiments in sem iconductor nanostructures<sup>16,17,18</sup>. For A L-GaAsPQW 's we propose an experimental setup where the e ciency of optical DNP will be enhanced by the proper insertion of a -doped layer of dierent nuclei at a speci c position. Calculations of the induced nuclear polarization also allow us to predict the nuclearm agnetic resonance shift in sem iconductor nanostructures.

The paper is organized as follows. In the next Section we present a theoretical derivation of DNP in samples with reduced dimensionality. Section III presents numerical estimations for the induced nuclear spin polarization and the resulting dipolar nuclear magnetic elds for an A IG aAs PQW . Section IV gives our conclusions.

#### II. DYNAM ICAL NUCLEAR POLARIZATION

D ynam ical nuclear polarization was theoretically described by O verhauser<sup>15</sup> in bulk m etallic samples. The interaction between nuclear and electronic spins leads to an enhanced nuclear spin polarization which can be m easured in NMR and TRFR experiments. For sem iconductor bulk m aterials such as G aA s, the DNP effect can be enhanced via optical techniques<sup>19,20</sup>. The sam e optical pumping technique was successfully used to polarized nuclei in quasi two-dimensional sem iconductor heterostructures  $^{8,21}$ . In this Section we investigate theoretically DNP in samples with reduced dimensionality such as quantum wells and quantum dots (QD).

The hyper ne interaction between electronic and nuclear spins is described by the Ham iltonian

$$H_n = \frac{8}{3} e_n (\sim_n e^2) (r_f);$$
 (1)

where n labels the nuclei, n and e are the nuclear and electron m agnetic m om ents,  ${\sim_{\rm n}}$  and  ${\sim_{\rm e}}$  are the P auli spin operators for the nucleus and electron, r r, represents the relative distance between the nuclear and electronic spins, and (r) is the D irac delta function. The H am iltonian describes a ip- op process for both electronic and nuclear spins in which the energy and the total angular m om entum are conserved. W e consider the interaction to be weak, so we can use perturbation theory to describe its e ects. To understand the dynam ics of the electronic and nuclear spins governed by the hyper ne interaction we consider the system to be in an external magnetic eld, B<sub>0</sub>, which partially orients the spins. We assume dephasing of electronic orbital information on timescales much faster ( 100fs) than either the precession of electron spins in momentum-dependent e ective magnetic elds<sup>22</sup> or nuclear decoherence tim es; this perm its us to neglect the momentum -dependent spin splitting of electronic states from the spin-orbit interaction<sup>22</sup>. The electronic spin polarization is assumed the same everywhere, described by the spin-up and spin-down populations N + (parallel to the applied eld) and N (antiparallel to the applied eld), respectively. On the other hand, the nuclear system will develop a position dependent polarization described by  $M_m$  ( $r_n$ ), m = I; I1;:::; I, where I is the nuclear spin quantum number. The hyper ne interaction will act to relax both the electronic and the nuclear spins, according to the following two equations<sup>23</sup>

$$\frac{dD}{dt} = \frac{D_0}{T_{1e}} + \frac{X}{n} + \frac{0}{T_{1n}(r)} (r_n) (r_n)$$
(2)

and

$$\frac{dD}{dt} = \frac{2I(I+1)(2I+1)}{3} X \frac{d(r_n)}{dt} :$$
(3)

Here  $D = N_{+} N_{-}$ ,  $(r_{n}) = M_{m+1}(r_{n}) M_{m}(r_{n})$ , and  $D_{0}$  and  $0_{0}(r_{n})$  are their therm alequilibrium values. The electronic and nuclear spin relaxation times are given by (see Refs. 9,23)

$$T_{1e}^{1} = \frac{1}{V} \frac{X}{n} \frac{1024^{3} e^{2} r_{R}^{2}}{9h(2I+1)} \frac{R}{dr} \frac{dr}{A}_{e}^{2}(r_{n}; r) f_{FD}^{0}(r)}{drdr} (4)$$

and

$$T_{1n}^{1}(\mathbf{r}_{n}) = \frac{512 \ ^{3} \ ^{2}_{e} \ ^{2}_{n} k_{B} T \ ^{R} d"A_{e}^{2}(\mathbf{r}_{n};") f_{FD}^{0}(")}{3hI(I+1)(2I+1)}; \quad (5)$$

where  $A_e(r_n; ")$  represents the ELDOS, T is the tem perature, and  $f_{FD}$  (") the Ferm i-D irac distribution function. The ELDOS at the nuclear position  $\boldsymbol{r}_n$  is

$$A_{e}(\mathbf{r}_{n};") = \begin{cases} X \\ j_{1}(\mathbf{r}_{n}) \\ j \end{cases} (" E_{1}); \qquad (6)$$

where 1 labels the state,  $E_1$  its energy, and  $_1(r_n)$  its wavefunction at the n'th nucleus. Equations (2) and (3) can be combined to obtain a general equation for the nuclear spin dynam ics

$$\frac{d (r_n)}{dt} = \frac{0 (r_n) (r_n)}{T_{1n} (r_n)} + \frac{1}{(2I+1) k_B T N'} \frac{D_0 D}{T_{1n} (r_n)};$$
  
R
(7)

where  $N' = \int drd"A_e(r;")f_{FD}^0$  ("). The above equation describes the nuclear spin dynam ics due to the hyper ne interaction. Additionally, the nuclei will relax through otherm echanism s as a result of interactions with phonons, in purities, electrons, and other nuclei. Such interactions should be included in any equation for the nuclear spin dynam ics, and they can be included by replacing  $1=T_{1n}$  ( $r_n$ ) with  $1=T_{1n}$  ( $r_n$ ) +  $1=T_n^0$  in the rst term on the right hand side (rhs) of Eq (7). Here  $T_n^0$  represents the nuclear spin relaxation time due to additional relaxation m echanism s. Note that such a replacement is not appropriate for the second term in the rhs of Eq. (7), as this term originates from the hyper ne interaction alone.

Equation (7) also assumes that nuclear spin di usion can be neglected. The nature of the sample determines whether or not nuclear spin di usion can be neglected. Paget<sup>24</sup> showed that in bulk G aAs di usion is very im – portant, and leads to an uniform polarization of the nuclei across the sample. To describe di usion the equation for the time and position dependence of the nuclear spin polarization has to be modied by adding a di usive term. However, often nuclear spin di usion appears negligible for low dimensional samples such as QW and QD<sup>14,25</sup>. In the following we will discuss the consequences of the DNP e ect in the absence of nuclear spin di usion. Such an assumption should work well for PQW 's, the system for which we will report speci c results<sup>9,14</sup>.

In DNP, spin polarized electrons created by absorbtion of polarized light or electrical injection<sup>25</sup> will transfer their polarization to the nuclei via the hyper ne interaction. We assume that the electronic polarization, D, is kept constant by continual resupply of spin polarized electrons. This would naturally be the case for DC electrical spin injection. For pulsed optical pumping, how ever, the spin-polarized electron population will vary on timescales corresponding to the time between pulses (13 ns). Here we rely on the vastly greater timescales of the nuclei | as the response times of the nuclei ( $T_{1n}$ ) are orders of m agnitude greater than 13 ns, the nuclei see an electron constant average electron spin polarization. Under these conditions the last term in Eq. (7) is independent of time and the time-dependent nuclear

polarization is

$$(r_n;t) = _0 + _{ind}(r_n) \ 1 \ \exp \ t \ \frac{1}{T_{1n}(r_n)} + \frac{1}{T_n^0}$$
(8)

where

$$_{\text{ind}}(\mathbf{r}_{n}) = \frac{1}{(2I+1)k_{\text{B}}TN} \frac{T_{n}^{0}}{T_{1n}(\mathbf{r}_{n}) + T_{n}^{0}} (D_{0} \quad D) \quad (9)$$

represents the induced nuclear polarization due to the hyper ne interaction. In general the nuclear polarization due to external magnetic elds,  $_0$ , is about 1%, suggesting that the large nuclear polarization originates from the hyper ne interaction.

Two di erent tim e regim es can be identi ed in Eq. (8). First, in the initial stages of the DNP process (t  $T_{eff}$ ; with  $T_{eff}^{1} = T_{1n}^{1} + T_{n}^{\circ 1}$ ), the nonequilibrium nuclear system m agnetization can be approximated as

$$(r_n;t) \quad ind (r_n) \frac{t}{T_{eff}}$$
: (10)

In general, at low tem peratures where the DNP process is e cient, the relaxation mechanism due to the hyper ne interaction is the dom inant one, making  $T_{1n}$  shorter than  $T_n^0$ . A coordingly, in the initial stage of the DNP process,  $(r_n;t) / j_1(r_n) ft$  (Ref. 9). On the other hand, in the second regime of the DNP process for t  $T_{eff}$ , the induced nuclear spin polarization from the hyper ne interaction will saturate at

$$(\mathbf{r}_{n};\mathbf{t}) = \mathbf{0} + \frac{1}{(2\mathbf{I}+1)\mathbf{k}_{\mathrm{B}}\mathbf{T}\mathbf{N}} \frac{\mathbf{T}_{n}^{0}}{\mathbf{T}_{1n}(\mathbf{r}_{n}) + \mathbf{T}_{n}^{0}} (\mathbf{D}_{0} \quad \mathbf{D})$$
(11)

## III. NUCLEAR SPIN POLARIZATION AND DIPOLAR MAGNETIC FIELDS

Large non-equilibrium nuclear polarizations produce real m agnetic elds that act both on the nuclear and on the electronic spins. A signi cant e ect of these elds is the shift of resonant frequencies in m agnetic resonance experiments associated with nuclei or electrons. Below we address primarily the e ects of DNP on NMR experiments; their eect on TRFR experiments will be reported elsew here<sup>26</sup>.

We determ ine the nuclear magnetic elds from the non-equilibrium occupation of the dierent states of the nuclear spin due to the DNP process, and we neglect the equilibrium polarization  $_0$  from the static magnetic eld. The induced nuclear spin polarization,

D

$$P = \frac{\underline{P}^{n} \ m \ M_{m}}{\underline{\Gamma}_{m} \ M_{m}} : \qquad (12)$$

For nanostructured m aterials P will depend on position, as nuclei in di erent regions of the sam ple overlap di erently with the electronic wavefunctions. A lso, the tim edependence of the DNP process will cause the nuclear spin polarization to depend on time as well. The induced nuclear magnetization is

;

$$M_{ind}(\mathbf{r}_{n}) = M_{m} M_{m}(\mathbf{r}_{n}) :$$
(13)

The observable physical quantity in NMR experiments, however, is the nuclear magnetic eld produced by this nonequilibrium magnetization. The position-dependent induced nuclearmagnetic eld can be calculated for layered structures by dividing the structure into this slabs stacked in the growth direction and labeled by  $z_n$ , and assuming that the nuclei in each slab have uniform magnetization. Nuclei in di erent slabs can have di erent magnetization due to the potential dependence of the nuclear relaxation time on the growth direction<sup>9</sup> due to a non-uniform ELDOS. The dipolar eld from the nuclei, if they are polarized perpendicular to the growth direction, is

$$B_{ind}(r_n) = {}_{0 n}M_{ind}(r_n);$$
 (14)

where  $_0$  represents the vacuum perm eability and  $_n$  the nuclear magneton. This magnetic eld will act both on the nuclei and the electrons, and for nuclei the electrons be measured as a shift in the resonance frequency in an NMR experiment. This elect is similar to the Knight shift<sup>27</sup>, and can be characterized by

$$(r_n) = g_n B_{ind}(r_n);$$
 (15)

where  $g_n$  is the nuclear g-factor. For low dimensional nanostructures the shift will depend on position. The total nuclear magnetic moment of the sample is

$$M = dr_{n n} M_{ind} (r_n) :$$
 (16)

For a PQW structure the system 's dispersion relations are quasi-two dimensional, and the total electronic wavefunction is a product between an envelope function, (z), and a B loch function, u (r),

$$_{jK}$$
 ( $r_n$ ) = exp [iK R]<sub>j</sub> (z) u ( $r_n$ ) : (17)

Based on this assumption the ELDOS is

$$A_{e}(\mathbf{r}_{n};") = \int_{j}^{X} (\mathbf{z}_{n}) \int_{j}^{2} N_{2D} (" E_{j(K=0)}); \quad (18)$$

where N<sub>2D</sub> is the density of states for a two-dimensional electron gas and (z) is the Heavyside step function. In the following we will consider an Al<sub>x</sub>Ga<sub>1 x</sub>As PQW (L = 1000 A) with x=0.07 in the center of the structure conned within two 100 A A  $l_{0:4}$ Ga<sub>0:6</sub>A sharriers. For this structure the value of the Bloch function at G a nuclei was already extracted in Ref. 9 and the envelope functions will be evaluated using a 14-band k p calculation? For all calculations we consider only the rst electronic conduction subband occupied and the electron spin polarization, D = 100%, much greater than the therm odynamic equilibrium one, D<sub>0</sub>. The additional nuclear spin



FIG.1: The growth-direction position dependence of the saturated induced nuclear spin polarization in the A IG aA sPQW for  $T_n^0 = 600$  s and di erent tem peratures (full line{T = 5K, dash line{T = 10K, and dash-dot line{T = 60K}.

relaxation time,  $T_n^0 = 600$  s, and is considered to be tem – perature independent<sup>29</sup>.

Figure 1 presents a quantitative plot of the saturated induced nuclear spin polarization,  $P_{sat}(r_n)$  as a function of position in the AlG aAs PQW at di erent temperatures. For fully polarized electrons (D = 100%) the induced nuclear spin polarization in the center of the PQW can be as high as 80%, decreasing drastically on the sides of the sample. The nuclear spin polarization also decreases as the temperature increases, m aking the DNP processe ective only at low temperatures. If higher electronic subbands were considered, the position dependence of the saturated nuclear spin polarization would change accordingly.

Figure 2 presents a quantitative plot of the induced nuclear magnetic ekl B  $_{ind}$  ( $r_n$ ;t) as a function of time and position across the A G aA s PQW for the same situation as in Fig. 1. The strong con nement, even of this shallow PQW structure, is relected in the large induced nuclear magnetic ekl at the center. The total response of the sam ple in NMR experiments will be mainly due to the central nuclei of the sam ple, suggesting that a more elective DNP can be realized by the insertion of active NMR nuclei at a particular grow the direction position in the sam ple. For higher conduction subband occupancy the prole of the induced nuclear ekl will change accordingly, as a result of a dilerent position dependent nuclear spin relaxation time due to the hyper ne interaction<sup>9</sup>.

In Fig. 3 we present the position dependence of the saturated induced nuclear magnetic eld for di erent values of the additional nuclear spin relaxation time,  $T_n^0$ , considering only the rst conduction subband occupied. As seen in Fig. 3(a) the full width at half maximum (FW HM) of the induced nuclear magnetic eld is strongly dependent on the additional relaxation mechanisms involving nuclear spins. At low temperatures,



FIG. 2: The time and position dependence of the induced nuclear dipolar magnetic eld in the AlGaAsPQW for  $T_n^0 = 600$  s.

where most of our calculations are performed, the dom inant nuclear spin relaxation mechanism is the hyperne interaction, and the measurem ent of additional nuclear spin relaxation times is very dicult. Fig 3 (b) presents the saturated induced nuclear magnetic eld for  $T_n^0 = 600 \text{ s in the presence of and in the absence of an$ applied electric eld along the growth direction for the PQW . The control is based on the manipulation of the ELDOS.Our calculation suggests the possibility of further controlling and m an ipulating the nuclear spin distribution in A IG aAs PQW .W hen a -doped layer of active nuclei is inserted within the PQW, the initial nuclear polarization of the nuclei in the layer can be directly controlled by electric elds. A dierent way to electrically control the induced position dependent nuclear eld would be to gate the PQW and control the hyper ne nuclear spin relaxation time through the electronic subband occupancy<sup>9,23</sup>. Dierent shapes and dierent position dependences of the induced nuclear eld are expected in this case.

Fig 4 (a) presents the calculated nuclear resonance shift for the A IG aA s PQW for di erent conduction subband occupancy at T = 5 K. This situation is relevant for a

-doped layer of active nuclei, and the nuclear resonance shift can reach 8.5 kHz. M oreover, for a -doped layer, the resonance shift is fully controllable with electric elds, both when the eld is used as a control over the electron con nement in the PQW or when the eld is used as a source of subband occupancy in the PQW . Fig 4 (b) shows the total nuclear m agnetic m om ent as a function of the electron density for di erent temperatures. As the electron density increases, the number of occupied conduction subbands will increase, and accordingly the nuclear m agnetic m om ent of the well will increase quasistepw ise. For the considered PQW the energy di erence between the minimum of two consecutive conduction sub-



FIG.3: (a) The saturation value of the induced nuclear polarization in the A IG aA s PQW for di erent values of the additional nuclear relaxation time (full line:  $T_n^0 = 3000$  s, dashed line:  $T_n^0 = 600$  s, and dotted line:  $T_n^0 = 60$  s). (b) The saturation value of the induced nuclear polarization in the A IG aA s PQW for  $T_n^0 = 600$  s at di erent values of the applied electric eld (full line: F = 0 kV/cm, dashed line: F = 20 kV/cm, and dotted line: F = 50 kV/cm).

bands is about E = 15 meV, meaning that at T = 30 K (dotted line) therm along earing of the Fermi function will suppress the stepw ise shape of the total nuclearm agnetic moment. For PQW 's with a greater dierence E the stepw ise shape will persist even at higher temperatures. The total nuclear magnetic moment for a xed electronic density depends on temperature, as  $T_{1n}$  and  $T_n^0$  have dierent temperature dependencies (in Fig. 4 (b) we considered  $T_{1n}$  T and  $T_n^0$  const?<sup>29</sup>).

#### IV. CONCLUSIONS

The DNP process is of considerable interest for sam ples with reduced dimensionality as it represents a path for highly e cient NMR and TRFR measurements. As a result of DNP, nuclei will produce e ective m agnetic elds which in turn will act both on the nuclear and electronic populations. The e ects of those magnetic elds should be observable in NMR and TRFR experiments as shifts in the resonant frequencies. U sually, as a result of the hyper ne interaction there will be at least two types of induced nuclear magnetic elds, a hyper ne nuclear magnetic eld and a dipolar magnetic eld. The hyperne magnetic eld acting on the nuclear population is an e ective magnetic eld induced by the polarized electronic population. There will be also a hyper ne eld created by the polarized nuclei acting on the electrons. Such hyper ne elds will induce a Knight shift in the nuclear resonant frequencies, and an O verhauser shift in the electronic resonant frequencies, respectively. On the other hand, the dipolar magnetic eld is a real magnetic



FIG.4: (a) The nuclear resonance frequency shift as function of position in the PQW for di erent conduction subband occupancy at T = 5 K (full line: single subband occupancy, dashed line: double subband occupancy, and dotted line: triple subband occupancy). (b) Total nuclear induced m agnetic moment as function of the electron density for di erent tem peratures (full line: T = 5 K, dashed line: T = 10 K, and dotted line: T = 30 K).

eld created as a result of nuclear spin polarization. The dipolar nuclear magnetic eld will be responsible for an additional shift in the resonant frequencies of both nuclear and electronic system s sim ilar to K night and O verhauser shifts, respectively.

For general low dimensional systems we described the dynam ics of the nuclear spins for optical pum ping of the electronic population. The resulting nuclear spin polarization is both time and position dependent. In the initial stage of the polarization process, the induced nuclear polarization is linearly dependent on time. For longer tim es the nuclear spin polarization saturates and is tim e independent. The position dependence of the induced nuclear spin polarization is a function of the electronic con nem ent across the system , and of various relaxation mechanisms acting on the nuclear spin. Consequently, the resonance shift induced by such a eld will be position dependent. D i erent experim ental setups will record di erent resonance shifts. For exam ple, if the sam ple is grown such that in the central region we have a -doped layer of a di erent nuclei than the host nuclei, the resonance shift for such a layer will strongly depend on its position across the well. On the other hand, in di erent experiments it may be that whole magnetic moment of the sample is recorded.

As a speci c example we calculated the e ects of the DNP process for an A G aAs PQW. The nuclear spin polarization can be as high as 80% at T = 5K for an initial electronic spin polarization of 100%. The nuclear spin polarization is concentrated in the central regions of the PWQ and depends also on temperature, being strongly reduced as the temperature increases. The DNP e ect

provides the potential to manipulate nuclear spins in sem iconductor nanostructures, making the nuclear spins an important candidate for new electronic devices. The particular geometry of the PQW permits a sensitive controlofnuclear spins with small electric elds.

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